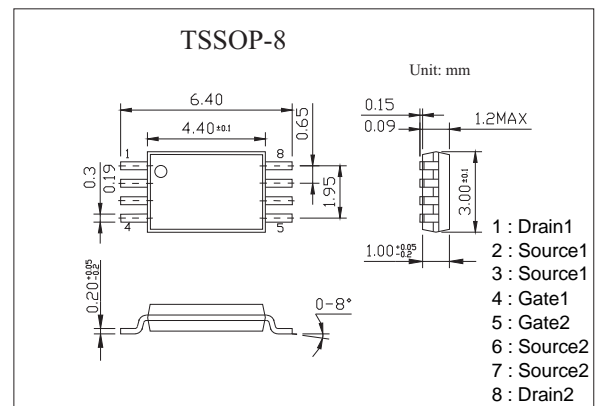
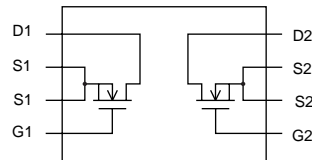


Dual N-Channel MOSFET

SI9926DY

■ Features

- $R_{DS(on)} \leq 0.032 \Omega$ @ $V_{GS} = 4.5 V$
- $R_{DS(on)} \leq 0.045 \Omega$ @ $V_{GS} = 2.5 V$.

■ Absolute Maximum Ratings $T_A = 25^\circ C$

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	V_{DS}	20	V	
Gate-Source Voltage	V_{GS}	± 10	V	
Continuous Drain Current	I_D	6.5	A	
Pulsed Drain Current	I_{DM}	20	A	
Maximum Power Dissipation	P_D	$T_A = 25^\circ C$	1.25	W
		$T_A = 70^\circ C$	0.8	W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	100	$^\circ C/W$	
Junction temperature and Storage temperature	T_j, T_{stg}	-55 to +150	$^\circ C$	

SI9926DY

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	V _{DSS}	V _{GS} = 0 V, I _D = 250 μA	20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 16V, V _{GS} = 0V			1	μA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250μA	0.5	1	1.5	V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0V, V _{GS} = ±8V			±100	nA
Drain-Source On-State Resistance *	R _{DS(on)}	V _{GS} = 4.5V, I _D = 6.5A		0.026	0.032	Ω
		V _{GS} = 2.5V, I _D = 5.4A		0.037	0.045	
On-State Drain Current *	I _{D(on)}	V _{DS} = 5V, V _{GS} = 4.5V	15			A
Forward Transconductance *	g _{fs}	V _{DS} = 5V, I _D = 3A		11		S
Input Capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1.0 MHz		700		pF
Output Capacitance	C _{oss}			175		pF
Reverse Transfer Capacitance	C _{rss}			85		pF
Total Gate Charge	Q _g	V _{DS} = 10V, V _{GS} = 4.5V, I _D = 3A		7	10	nC
Gate-Source Charge	Q _{gs}			1.2		
Gate-Drain Charge	Q _{gd}			1.9		
Turn-On Delay Time	t _{d(on)}	V _{DD} = 10V I _D = 1A, V _{GS} = 4.5V, R _G = 6 Ω		8	16	ns
Rise Time	t _r			10	18	
Turn-Off Delay Time	t _{d(off)}			18	29	
Fall Time	t _f			5	10	
Maximum Continuous Drain-Source Diode Forward Current	I _S				1.3	A
Diode Forward Voltage *	V _{SD}	I _S = 1.3A, V _{GS} = 0 V		0.65	1.2	V

* Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.

■ Marking

Marking	9926D
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